

PBSS5350D

50 V, 3 A PNP low VCEsat (BISS) transistor Rev. 6 — 28 June 2011

Product data sheet

Product profile 1.

1.1 General description

PNP low V_{CEsat} Breakthrough In Small Signal (BISS) transistor in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4350D

1.2 Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- High current capability
- High efficiency due to less heat generation
- AEC-Q101 qualified
- Smaller Printed-Circuit Board (PCB) area than for conventional transistors

1.3 Applications

- Supply line switching circuits
- Battery management applications
- DC-to-DC conversion

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
I _C	collector current		-	-	-3	Α
I _{CM}	peak collector current		-	-	-5	Α
R _{CEsat}	collector-emitter saturation resistance	$I_C = -2 \text{ A}$; $I_B = -200 \text{ mA}$; pulsed; $t_p \le 300 \text{ µs}$; $\delta \le 0.02$; $T_{amb} = 25 \text{ °C}$	-	120	150	mΩ



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2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	С	collector	G. G. G.	4.0.5.0
2	С	collector	<u> </u>	1, 2, 5, 6
3	В	base	0	3 —
4	Е	emitter	<u> </u>	
5	С	collector	SOT457 (TSOP6)	4 sym030
6	С	collector		5,

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS5350D	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457

4. Marking

Table 4. Marking codes

Type number	Marking code
PBSS5350D	53

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5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-60	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-3	Α
I _{CM}	peak collector current			-	-5	Α
I _{BM}	peak base current			-	-1	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	<u>[1]</u>	-	600	mW
			[2]	-	750	mW
			[3]	-	1200	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for collector 1 cm².

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance	in free air	<u>[1]</u>	-	-	208	K/W
	from junction to ambient		[2]	-	-	160	K/W
	ambient	pulsed; $t_p \le 50$ ms; $\delta \le 0.5$.; in free air	[2]	-	-	100	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

^[3] Device mounted on an FR4 4-layer PCB.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

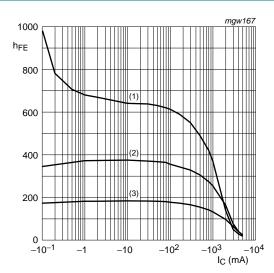
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7. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	$V_{CB} = -50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nΑ
	current	V _{CB} = -50 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
h _{FE}	DC current gain	V_{CE} = -2 V; I_{C} = -500 mA; T_{amb} = 25 °C	200	-	-	
		V_{CE} = -2 V; I_{C} = -1 A; pulsed; $t_{p} \le 300 \text{ µs}; \delta \le 0.02 ; T_{amb}$ = 25 °C	200	-	-	
		V_{CE} = -2 V; I_{C} = -2 A; pulsed; $t_{p} \le 300 \text{ µs}; \delta \le 0.02 ; T_{amb}$ = 25 °C	100	-	-	
OLSai	collector-emitter saturation voltage	I_C = -500 mA; I_B = -50 mA; T_{amb} = 25 °C	-	-	-100	mV
		$I_C = -1 \text{ A}; I_B = -50 \text{ mA}; T_{amb} = 25 \text{ °C}$	-	-	-180	mV
		$I_C = -2 \text{ A}$; $I_B = -200 \text{ mA}$; pulsed;	-	-	-300	mV
R _{CEsat}	collector-emitter saturation resistance	$t_p \le 300 \text{ μs; } δ \le 0.02 \text{ ; } T_{amb} = 25 \text{ °C}$	-	120	150	mΩ
V_{BEsat}	base-emitter saturation voltage		-	-	-1.2	V
V_{BEon}	base-emitter turn-on voltage	$V_{CE} = -2 \text{ V; } I_{C} = -1 \text{ A; pulsed;}$ $t_{p} \le 300 \text{ µs; } \delta \le 0.02 \text{ ; } T_{amb} = 25 \text{ °C}$	-	-	-1.1	V
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C	100	-	-	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	-	40	pF

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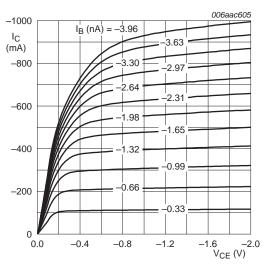
$$V_{CE} = -2 V$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = -55$ °C

Fig 1. DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig 2. Collector current as a function of collector-emitter voltage; typical values

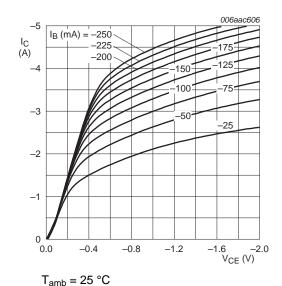
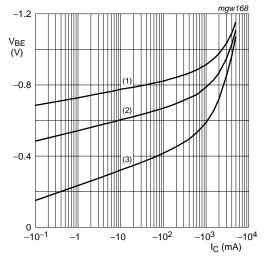


Fig 3. Collector current as a function of collector-emitter voltage; typical values



 $V_{CE} = -2 V$

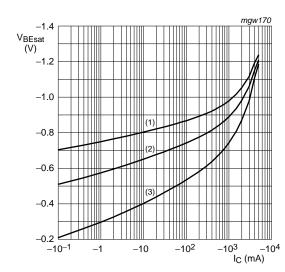
(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3) $T_{amb} = 150 \, ^{\circ}C$

Fig 4. Base-emitter voltage as a function of collector current; typical values

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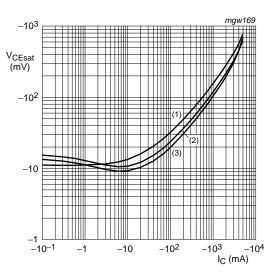
$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = -55$$
 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 5. Base-emitter saturation voltage as a function of collector current; typical values



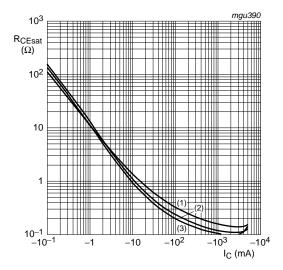
$$I_{\rm C}/I_{\rm B}=10$$

(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55$$
 °C

Fig 6. Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig 7. Collector-emitter saturation resistance as a function of collector current; typical values

Package outline

Plastic surface-mounted package (TSOP6); 6 leads **SOT457** В = v M A 6 pin 1 index 3 ⊕ w M B detail X **DIMENSIONS** (mm are the original dimensions) UNIT Е Q Lp 0.40 1.1 0.26 3.1 1.7 3.0 0.6 0.33 0.95 0.2 0.2 0.1 mm 0.013 0.25 0.10 1.3 2.5 REFERENCES EUROPEAN PROJECTION OUTLINE ISSUE DATE VERSION

Package outline SOT457 (TSOP6)

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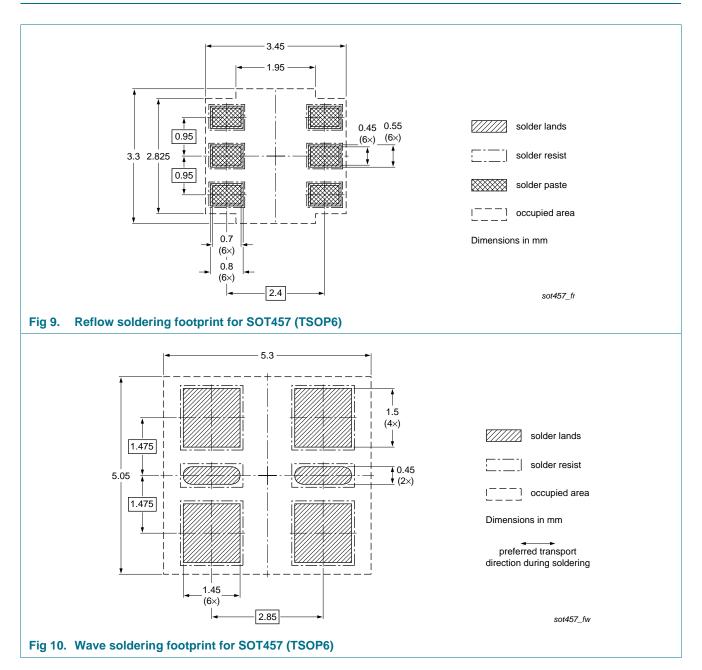
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SOT457

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9. Soldering



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10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5350D v.6	20110628	Product data sheet	-	PBSS5350D v.5
Modifications:	 5 "Limiting values" 	: P _{tot} conditions updated.		
PBSS5350D v.5	20110323	Product data sheet	-	PBSS5350D v.4
PBSS5350D v.4	20011113	Product specification	-	PBSS5350D v.3
PBSS5350D v.3	20010713	Product specification	-	PBSS5350D v.2
PBSS5350D v.2	20010126	Product specification	-	PBSS5350D v.1
PBSS5350D v.1	20000308	Product specification	-	-

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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